

Zener Voltage Regulators

200 mW SOD-323 Surface Mount

This series of Zener diodes is packaged in a SOD-323 surface mount package that has a power dissipation of 200 mW. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

Specification Features:

- High demand voltage range (3.6V-36V)
- Steady State Power Rating of 200 mW
- Small Body Outline Dimensions: 0.067" x 0.049"(1.7 mm x 1.25 mm)
- Low Body Height: 0.035" (0.9 mm)
- Package Weight: 4.507 mg/unit
- ESD Rating of Class 3 per Human Body Model
- Pb-Free package is available.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.
- We declare that the material of product compliance with RoHS requirements.

Mechanical Characteristics:

CASE: Void-free, transfer-molded plastic

FINISH: All external surfaces are corrosion resistant

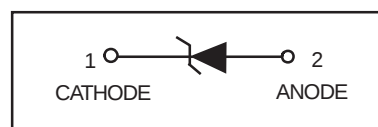
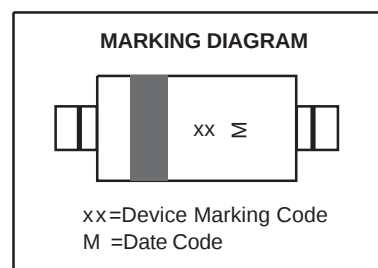
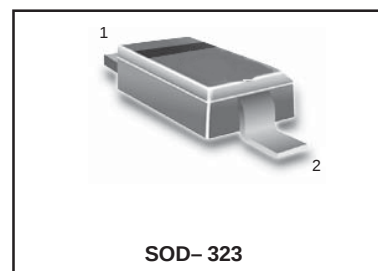
MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by polarity band

FLAMMABILITY RATING: UL94 V-0

MOUNTING POSITION: Any



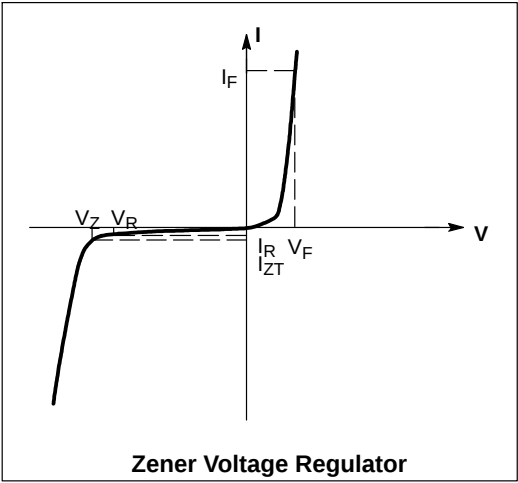
ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Parameter	Symbol	Limits	Unit
Power dissipation	P	200	mW
Thermal Resistance from Junction to Ambient	R _{θJA}	635	°C/W
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C
Operating temperature	T _{opr}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise noted,
 $V_F = 0.9\text{ V Max. @ } I_F = 10\text{ mA}$ for all types)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_{ZK}	Reverse Current
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F
ΘV_Z	Maximum Temperature Coefficient of V_Z
C	Max. Capacitance @ $V_R = 0$ and $f = 1\text{ MHz}$



ELECTRICAL CHARACTERISTICS (Ta=25°C)

Device	Device Marking	Zener voltage			Operating resistance		Rising operating resistance		Reverse current	
		V _Z (V)			Z _Z (Ω)		Z _{ZK} (Ω)		I _R (μA)	
		Min.	Max.	I _Z (mA)	Max.	I _Z (mA)	Max.	I _Z (mA)	Max.	V _R (V)
UDZS2.0B	02	2.020	2.200	5	100	5	1000	0.5	120	0.5
UDZS2.2B	12	2.220	2.410	5	100	5	1000	0.5	120	0.7
UDZS2.4B	22	2.430	2.630	5	100	5	1000	0.5	100	1.0
UDZS2.7B	32	2.690	2.910	5	110	5	1000	0.5	100	1.0
UDZS3.0B	42	3.010	3.220	5	120	5	1000	0.5	50	1.0
UDZS3.3B	52	3.320	3.530	5	120	5	1000	0.5	20	1.0
UDZS3.6B	62	3.600	3.845	5	100	5	1000	1.0	10	1.0
UDZS3.9B	72	3.890	4.160	5	100	5	1000	1.0	5	1.0
UDZS4.3B	82	4.170	4.430	5	100	5	1000	1.0	5	1.0
UDZS4.7B	92	4.550	4.750	5	100	5	800	0.5	2	1.0
UDZS5.1B	A2	4.980	5.200	5	80	5	500	0.5	2	1.5
UDZS5.6B	C2	5.490	5.730	5	60	5	200	0.5	1	2.5
UDZS6.2B	E2	6.060	6.330	5	60	5	100	0.5	1	3.0
UDZS6.8B	F2	6.650	6.930	5	40	5	60	0.5	0.5	3.5
UDZS7.5B	H2	7.280	7.600	5	30	5	60	0.5	0.5	4.0
UDZS8.2B	J2	8.020	8.360	5	30	5	60	0.5	0.5	5.0
UDZS9.1B	L2	8.850	9.230	5	30	5	60	0.5	0.5	6.0
UDZS10B	05	9.770	10.210	5	30	5	60	0.5	0.1	7.0
UDZS11B	15	10.760	11.220	5	30	5	60	0.5	0.1	8.0
UDZS12B	25	11.740	12.240	5	30	5	80	0.5	0.1	9.0
UDZS13B	35	12.910	13.490	5	37	5	80	0.5	0.1	10.0
UDZS15B	45	14.340	14.980	5	42	5	80	0.5	0.1	11.0
UDZS16B	55	15.850	16.510	5	50	5	80	0.5	0.1	12.0
UDZS18B	65	17.560	18.350	5	65	5	80	0.5	0.1	13.0
UDZS20B	75	19.520	20.390	5	85	5	100	0.5	0.1	15.0
UDZS22B	85	21.540	22.470	5	100	5	100	0.5	0.1	17.0
UDZS24B	95	23.720	24.780	5	120	5	120	0.5	0.1	19.0
UDZS27B	A5	26.190	27.530	5	150	5	150	0.5	0.1	21.0
UDZS30B	C5	29.190	30.690	5	200	5	200	0.5	0.1	23.0
UDZS33B	E5	32.150	33.790	5	250	5	250	0.5	0.1	25.0
UDZS36B	F5	35.070	36.870	5	300	5	300	0.5	0.1	27.0

* Not production

Notes) 1. The Zener voltage (V_Z) is measured 40ms after power is supplied.2. The operating resistances (Z_Z, Z_{ZK}) are measured by superimposing a minute alternating current on the regulated current (I_Z).

ELECTRICAL CHARACTERISTIC CURVES (Ta=25°C)

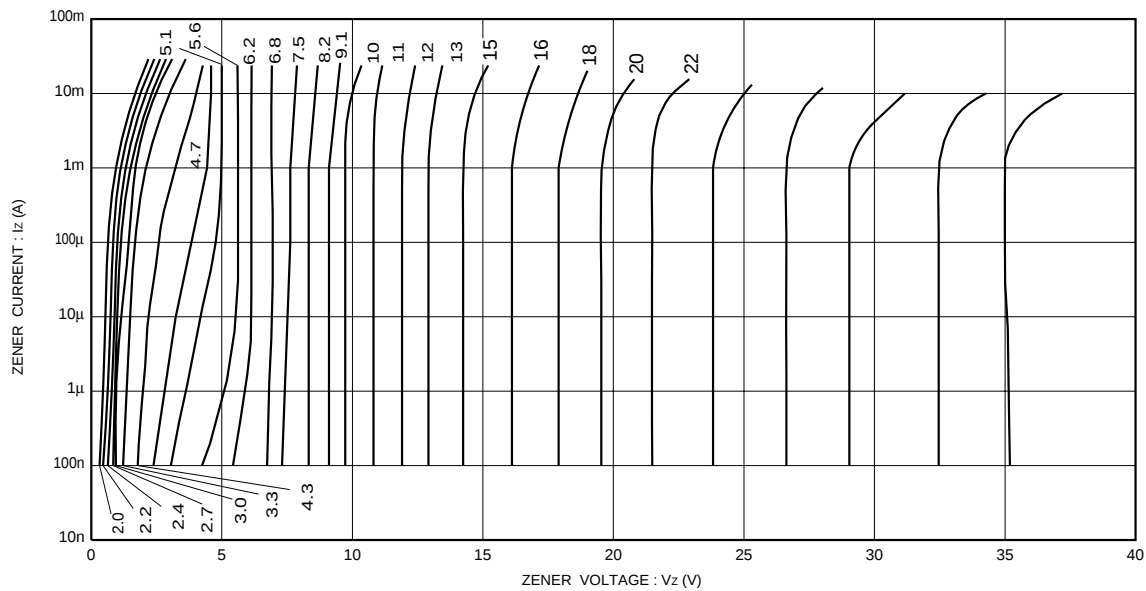


Fig.1 Zener voltage characteristics

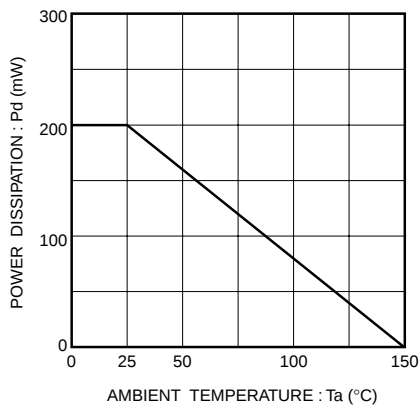


Fig.2 Derating curve

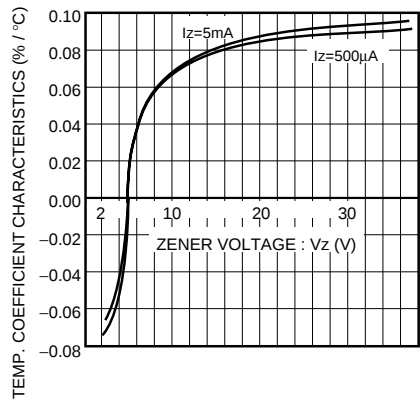
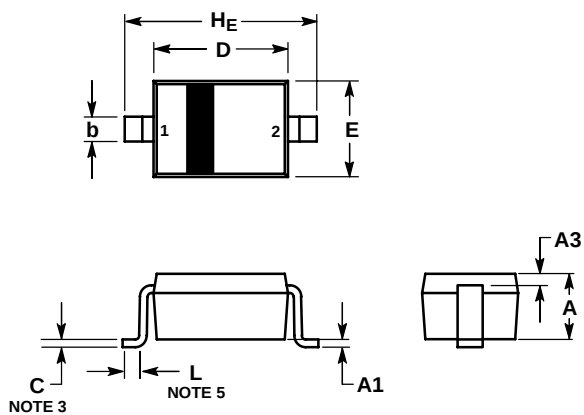


Fig.3 Zener voltage-temp. coefficient characteristics

SOD-323



- NOTES:
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 - 2. CONTROLLING DIMENSION: MILLIMETERS.
 - 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
 - 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
 - 5. DIMENSION L IS MEASURED FROM END OF RADIUS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
C	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
E	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
H _E	2.30	2.50	2.70	0.090	0.098	0.105

SOLDERING FOOTPRINT*

